NEC

NPN SILICON TRANSISTOR

2SC1845

DESCRIPTION

The 2SC1845 is the best for use as the middle range amplifier in Hi-Fi stereo control amplifiers, power amplifiers, and etc.

FEATURES

• High Voltage.

V_{CEO} : 120 V

• Low Output Capacitance. Cob : 1.6 pF TYP. (VCB = 30 V)

• High hee.

 h_{FE} : 600 TYP. (V_{CE} = 6.0 V, I_{C} = 1.0 mA)

NV: 25 mV TYP. (See test Circuit.) Super Low Noise.

ABSOLUTE MAXIMUM RATINGS

Maximum Temperatures

Storage Temperature-55 to +125 °C Junction Temperature+125 °C Maximum

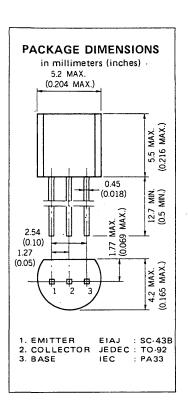
Maximum Power Dissipation (Ta = 25 $^{\circ}$ C)

Total Power Dissipation 500 mW

Maximum Voltages and Currents (Ta = 25 °C)

V_{CBO} Collector to Base Voltage 120 V V_{CEO} Collector to Emitter Voltage 120 V V_{EBO} Emitter to Base Voltage 5.0 V Collector Current 50 mA lc 1_B

Base Current 10 mA



ELECTRICAL CHARACTERISTICS (Ta = 25 °C)

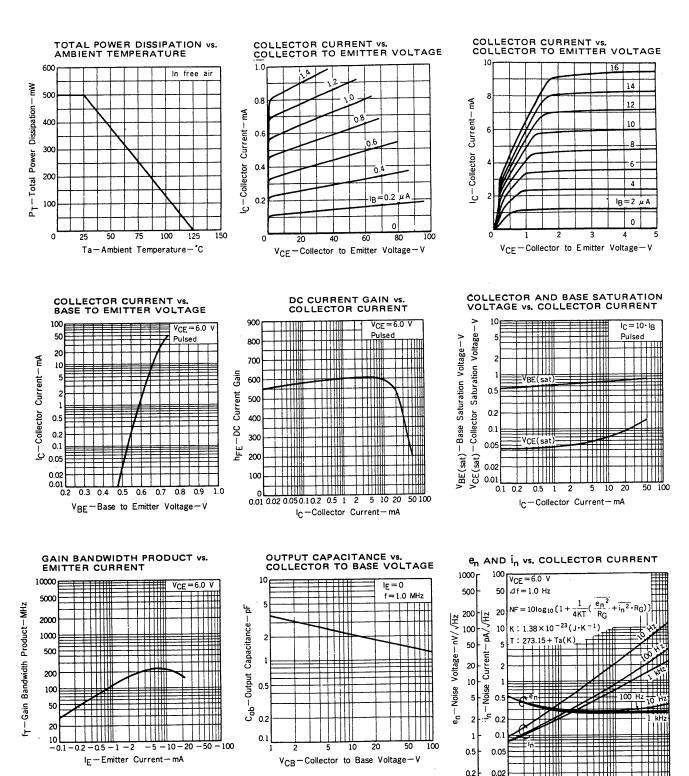
SYMBOL	CHARACTERISTIC	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
hFE1	DC Current Gain	150	580		_	V _{CE} = 6.0 V, I _C = 0.1 mA
hFE2	DC Current Gain	200	600	1200	_	$V_{CE} = 6.0 \text{ V, } I_{C} = 1.0 \text{ mA}$
fŢ	Gain Bandwidth Product	50	110		MHz	$V_{CE} = 6.0 \text{ V, } I_{E} = -1.0 \text{ mA}$
Cob	Output Capacitance		1.6	2.5	pF	$V_{CB} = 30 \text{ V}, I_E = 0, f = 1.0 \text{ MHz}$
NV	Noise Voltage		25	40	mV	$V_{CE} = 5.0 \text{ V}, I_{C} = 1.0 \text{ mA}, R_{G} = 100 \text{ k}\Omega$ $G_{V} = 80 \text{ dB}, f = 10 \text{ Hz to } 1.0 \text{ kHz}$
ICBO	Collector Cutoff Current			50	nΑ	V _{CB} = 120 V, I _E = 0
IEBO	Emitter Cutoff Current			50	nA	$V_{EB} = 5.0 \text{ V, } I_{C} = 0$
VBE	Base to Emitter Voltage	0.55	0.59	0.65	V	$V_{CE} = 6.0 \text{ V, } I_{C} = 1.0 \text{ mA}$
V _{CE(sat)}	Collector Saturation Voltage		0.07	0.30	V	$I_C = 10 \text{ mA}, I_B = 1.0 \text{ mA}$

Classification of h_{FE2}

ĺ	Rank	Р	F	E	U			
	Range	200 – 400	300 - 600	400 - 800	600 — 1200			

hFE Test Conditions : $V_{CE} = 6.0 \text{ V}$, $I_{C} = 1.0 \text{ mA}$

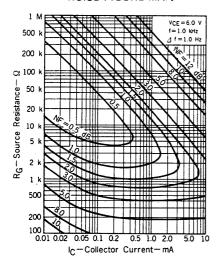
TYPICAL CHARACTERISTICS (Ta = 25 °C unless otherwise noted)



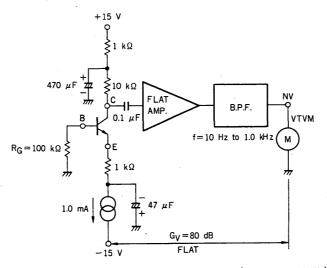
0.1 L

0.05 0.1 0.2 0.5 1 2 I_C—Collector Current—mA

NOISE FIGURE MAP.



NOISE VOLTAGE TEST CIRCUIT



 $\rm V_{CE} \buildrel 5$ V, $\rm I_{C} = 1.0$ mA, $\rm R_{G} = 100~k\Omega$, $\rm G_{V} = 80~dB, FLAT(f=10~Hz~to~1.0~kHz)$